

8/2403

	L #	Hits	Search Text	DBs
1	L1	10583	((optical or laser) near3 (record\$4 or storage or storing)).ti,ab.	USPA T; US-PG PUB
2	L2	10646	((optical or laser or compact) near3 (disk or disc)).ti,ab.	USPA T; US-PG PUB
3	L3	21379 8	(react\$4 or alloy\$4 or diffus\$4).ti,ab.	USPA T; US-PG PUB
4	L4	15541 0	mix\$4.ti,ab.	USPA T; US-PG PUB
5	L5	737	(1 or 2) and (3 or 4)	USPA T; US-PG PUB
6	L6	256	430/270.12.ccls.	USPA T; US-PG PUB
7	L7	759	428/64.4.ccls.	USPA T; US-PG PUB
8	L8	118	5 and (6 or 7)	USPA T; US-PG PUB
9	L9	70674	oxide.ti,ab.	USPA T; US-PG PUB
10	L10	33	5 and 9	USPA T; US-PG PUB
11	L11	28	10 not 8	USPA T; US-PG PUB
12	L12	7675	(transparent near3 (layer or film)).ti,ab.	USPA T; US-PG PUB
13	L13	6441	(reflect\$6 near3 (layer or film)).ti,ab.	USPA T; US-PG PUB

	L #	Hits	Search Text	DBs
14	L14	57605	interfac\$6.ti,ab.	USPA T; US-PG PUB
15	L15	20	5 and 12 and 13	USPA T; US-PG PUB
16	L16	8	15 not 8	USPA T; US-PG PUB
17	L17	17	5 and 14	USPA T; US-PG PUB
18	L18	12	17 not 8	USPA T; US-PG PUB
19	L19	87079	(optical or laser) near3 (record\$4 or storage or storing)	EPO; JPO; DERW ENT; IBM_T DB
20	L20	10510 2	(optical or laser or compact) near3 (disk or disc)	EPO; JPO; DERW ENT; IBM_T DB
21	L21	28286 31	react\$4 or alloy\$4 or diffus\$4 or mix\$4	EPO; JPO; DERW ENT; IBM_T DB
22	L22	37786 1	(layer or film) with 21	EPO; JPO; DERW ENT; IBM_T DB
23	L23	7048	(19 or 20) and 22	EPO; JPO; DERW ENT; IBM_T DB

	L #	Hits	Search Text	DBs
24	L25	103729	(si or silicon or ge or germanium or gap or gallium or inp or indium or gaas or inas or gasb or insb or oxide) same 22	EPO; JPO; DERW ENT; IBM_T DB
25	L26	1678	23 and 25	EPO; JPO; DERW ENT; IBM_T DB
26	L27	85953	transparent near3 (layer or film)	EPO; JPO; DERW ENT; IBM_T DB
27	L28	56166	reflect\$6 near3 (layer or film)	EPO; JPO; DERW ENT; IBM_T DB
28	L30	243758	interfac\$6	EPO; JPO; DERW ENT; IBM_T DB
29	L31	458	(19 or 20) and 21 and 27 and 28	EPO; JPO; DERW ENT; IBM_T DB
30	L32	6	30 and 31	EPO; JPO; DERW ENT; IBM_T DB
31	L34	177693	(si or silicon or ge or germanium or gap or gallium or inp or indium or gaas or inas or gasb or insb or oxide) same (react\$4 or diffus\$4)	EPO; JPO; DERW ENT; IBM_T DB
32	L35	602	(19 or 20) and 34	EPO; JPO; DERW ENT; IBM_T DB

	L #	Hits	Search Text	DBs
33	L36	23779 2	(thermal\$4 or heat\$4) near5 21	EPO; JPO; DERW ENT; IBM_T DB
34	L37	37653	(si or silicon or ge or germanium or gap or gallium or inp or indium or gaas or inas or gasb or insb or oxide) same 36	EPO; JPO; DERW ENT; IBM_T DB
35	L38	69046	(optical or laser) adj3 (record\$4 or storage or storing)	EPO; JPO; DERW ENT; IBM_T DB
36	L39	10150 1	(optical or laser or compact) adj3 (disk or disc)	EPO; JPO; DERW ENT; IBM_T DB
37	L40	19	37 and 38 and 39	EPO; JPO; DERW ENT; IBM_T DB
38	L41	21802 0	(thermal\$4 or heat\$4) near5 (react\$4 or alloy\$4 or mix\$4)	EPO; JPO; DERW ENT; IBM_T DB
39	L42	70	38 and 39 and 41	EPO; JPO; DERW ENT; IBM_T DB
40	L43	27440 6	(thermal\$4 or heat\$4).ti,ab.	USPA T; US-PG PUB
41	L44	21494	(3 or 4) near5 43	USPA T; US-PG PUB

	L #	Hits	Search Text	DBs
42	L45	46	(1 or 2) and 44	USPA T; US-PG PUB
43	L46	30	45 not 8	USPA T; US-PG PUB
44	L47	15666 4	react\$4.ti,ab.	USPA T; US-PG PUB
45	L48	168	(1 or 2) and 47	USPA T; US-PG PUB
46	L49	141	48 not 8	USPA T; US-PG PUB